## Tested By: Jay Copti

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## LSC Style Detector Measured Parameters

All transimpedance measurements are referred to plane of the physical output connector and include the effect of the voltage divider created by the $50 \Omega$ termination. All notch rejection ratios are relative to the magnitude of the transimpedance at the respective RF detection center frequency of the given RF output port.

| Parameter | Value |  |
| :---: | :---: | :---: |
| Detector serial number | S1300529 |  |
| Detector schematic D\# and revision | D1101994-v3 |  |
| Diode element manufacturer's serial number | 6534 |  |
| Quiescent DC current (amps at +18 VDC) | 69.7 mA |  |
| Quiescent DC current (amps at -18 VDC) | 92.1 mA |  |
| PD bias regulator output voltage (VDC) | 5.04 VDC |  |
| RF opamp positive voltage regulator (VDC) | 5.86 VDC |  |
| RF opamp negative voltage regulator (VDC) | -6.08 VDC |  |
| Audio opamp positive voltage regulator (VDC) | 14.77 VDC |  |
| Audio opamp negative voltage regulator (VDC) | -15.38 VDC |  |
| DC path transimpedance and zero light offset ( $\Omega / \mathrm{mVDC}$ at BNC out) | 099 ת | 0.4 mVDC |
| DC path transimpedance and zero light offset ( $\Omega / \mathrm{mVDC}$ at differential out) | 199 ת | 1.00 mVDC |
| DC path zero frequency ( Hz ) | 0.2 Hz |  |
| DC path pole frequency ( Hz ) | 2.4 Hz |  |
| Inferred DC path shot noise limited input photo sensitivity (mA) at 100 Hz measured at differential output | 3.4 mA |  |
| RF detection center frequency ( MHz ), f low | 9 MHz |  |
| RF detection center frequency ( MHz ), f hi | 45 MHz |  |
| Notch frequencies ( MHz ) used in design | 18, 36, 54, 90 MHz |  |
| F low feedback notch frequency | N/A |  |


| F hi feedback notch frequency | N/A |  |
| :---: | :---: | :---: |
| Rejection (dB) at notch1 (f low) | -29.6 dB |  |
| Rejection (dB) at notch2 (f low) | -33.9 dB |  |
| Rejection (dB) at notch3 (f low) | -35.7 dB |  |
| Rejection (dB) at notch4 (f low) | -32.0 dB |  |
| Rejection (dB) f low to f hi | -32.7 dB |  |
| Rejection (dB) at notch1 (f hi) | -51.2 dB |  |
| Rejection (dB) at notch2 (f hi) | -34.4 dB |  |
| Rejection (dB) at notch3 (f hi) | -30.2 dB |  |
| Rejection (dB) at notch4 (f hi) | -34.5 dB |  |
| Rejection (dB) f hi to f low | $-54.7 \mathrm{~dB}$ |  |
| Transimpedance ( $\Omega$ ) at f low (note PD Current) | 438 ת | 10.02 mA |
| RF dark/light noise used for f low Trans-Z | -127.0 dBm/Hz | -118.1 dBm/Hz |
| Transimpedance ( $\Omega$ ) at f hi (note PD Current) | $684 \Omega$ | 10.02 mA |
| RF dark/light noise used for f hi Trans-Z | -122.2 dBm/Hz | -114.1 dBm/Hz |
| RF preamp used during testing (noise/gain) | 143.2 dBm/Hz | 20.4 dB |
| flow , shot-noise limited input sensitivity (mA) | 1.45 mA |  |
| f hi, shot-noise limited input sensitivity (mA) | 1.82 mA |  |
| Test input transconductance at f1(mA/V) | 17.1 mA/V |  |
| Test switch isolation at f1 (dB) | 29.4 dB |  |
| Test input transconductance at f2(mA/V) | $24.7 \mathrm{mA/V}$ |  |
| Test switch isolation at $\mathrm{f} 2(\mathrm{~dB})$ | 27.6 dB |  |

